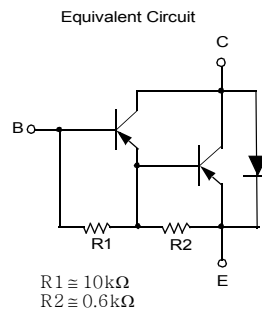
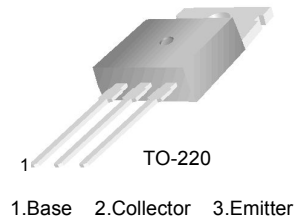


TIP105/TIP106/TIP107 PNP Epitaxial Silicon Darlington Transistor

- Monolithic Construction With Built In Base-Emitter Shunt Resistors
- High DC Current Gain : $h_{FE}=1000$ @ $V_{CE}=-4V$, $I_C=-3A$ (Min.)
- Collector-Emitter Sustaining Voltage
- Low Collector-Emitter Saturation Voltage
- Industrial Use
- Complementary to TIP100/101/102



Absolute Maximum Ratings* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage : TIP105	- 60	V
	: TIP106	- 80	V
	: TIP107	- 100	V
V_{CEO}	Collector-Emitter Voltage : TIP105	- 60	V
	: TIP106	- 80	V
	: TIP107	- 100	V
V_{EBO}	Emitter-Base Voltage	- 5	V
I_C	Collector Current (DC)	- 8	A
I_{CP}	Collector Current (Pulse)	- 15	A
I_B	Base Current (DC)	- 1	A
P_C	Collector Dissipation ($T_a=25^\circ\text{C}$)	2	W
	Collector Dissipation ($T_C=25^\circ\text{C}$)	80	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics* $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage : TIP105 : TIP106 : TIP107	$I_C = -30\text{mA}, I_B = 0$	-60 -80 -100			V V V
I_{CEO}	Collector Cut-off Current : TIP105 : TIP106 : TIP107	$V_{CE} = -30\text{V}, I_B = 0$ $V_{CE} = -40\text{V}, I_B = 0$ $V_{CE} = -50\text{V}, I_B = 0$			-50 -50 -50	μA μA μA
I_{CBO}	Collector Cut-off Current : TIP105 : TIP106 : TIP107	$V_{CB} = -60\text{V}, I_E = 0$ $V_{CB} = -80\text{V}, I_E = 0$ $V_{CB} = -100\text{V}, I_E = 0$			-50 -50 -50	μA μA μA
I_{EBO}	Emitter Cut-off Current	$V_{BE} = -5\text{V}, I_C = 0$			-2	mA
h_{FE}	DC Current Gain	$V_{CE} = -4\text{V}, I_C = -3\text{A}$ $V_{CE} = -4\text{V}, I_C = -8\text{A}$	1000 200		20000	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -3\text{A}, I_B = -6\text{mA}$ $I_C = -8\text{A}, I_B = -80\text{mA}$			-2 -2.5	V V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = -4\text{V}, I_C = -8\text{A}$			-2.8	V
C_{ob}	Output Capacitance	$V_{CB} = -10\text{V}, I_E = 0, f = 0.1\text{MHz}$			300	pF

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

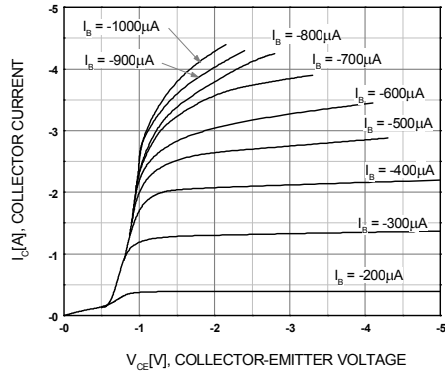


Figure 1. Static Characteristic

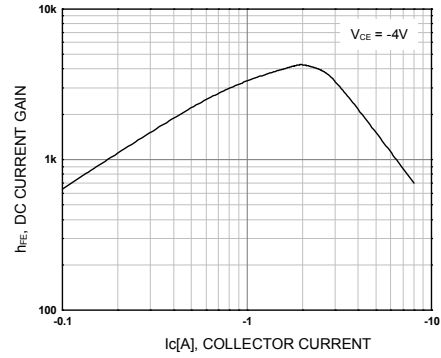


Figure 2. DC current Gain

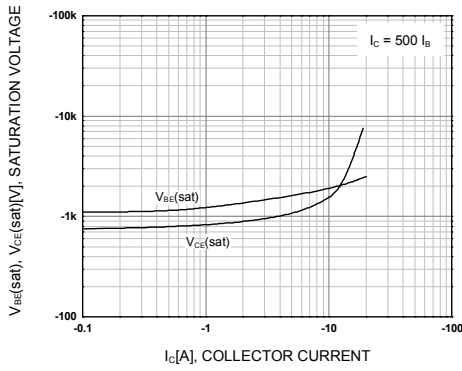


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

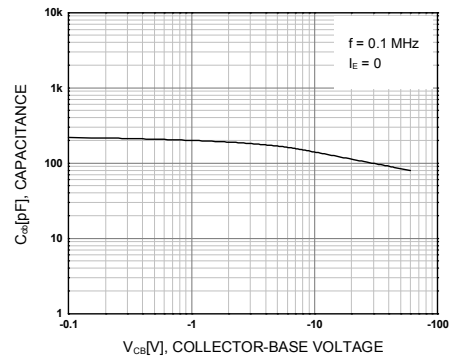


Figure 4. Collector Output Capacitance

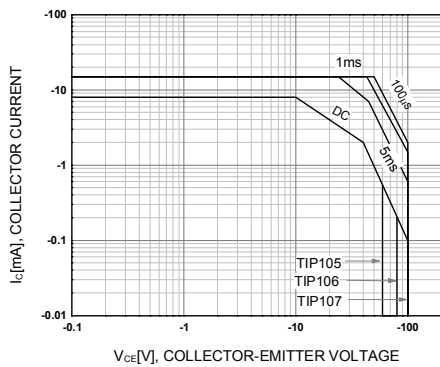


Figure 5. Safe Operating Area

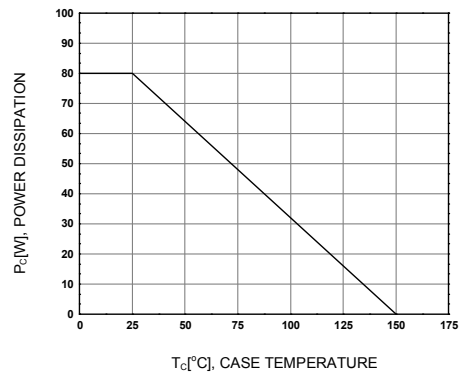
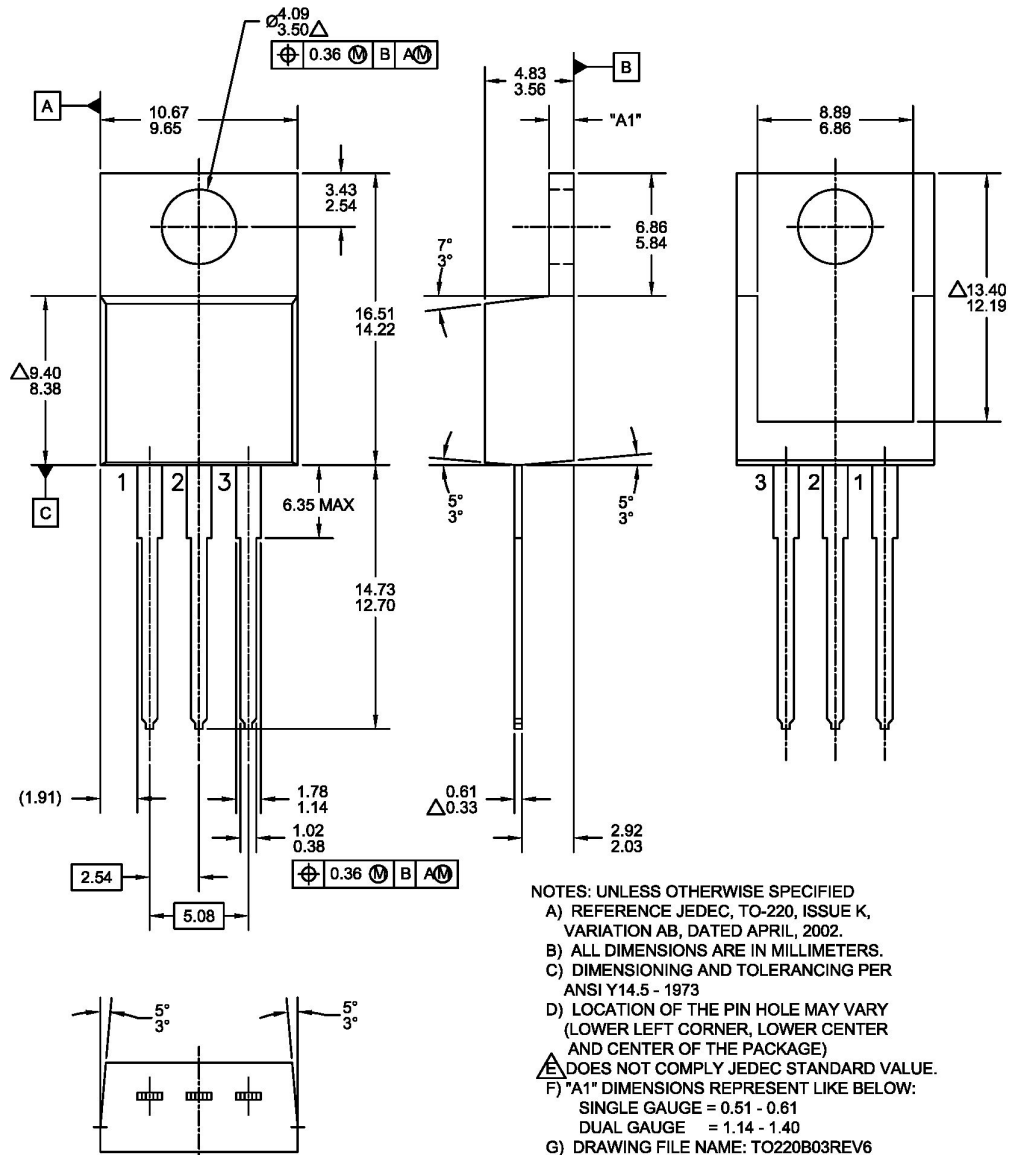


Figure 6. Power Derating

Mechanical Dimensions

TO220



- NOTES: UNLESS OTHERWISE SPECIFIED
- REFERENCE JEDEC, TO-220, ISSUE K, VARIATION AB, DATED APRIL, 2002.
 - ALL DIMENSIONS ARE IN MILLIMETERS.
 - DIMENSIONING AND TOLERANCING PER ANSI Y14.5 - 1973
 - LOCATION OF THE PIN HOLE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)
 - DOES NOT COMPLY JEDEC STANDARD VALUE.
 - "A1" DIMENSIONS REPRESENT LIKE BELOW:
SINGLE GAUGE = 0.51 - 0.61
DUAL GAUGE = 1.14 - 1.40
 - DRAWING FILE NAME: TO220B03REV6

TIP105/TIP106/TIP107 — PNP Epitaxial Silicon Darlington Transistor



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F ®	MICROCOUPLER™	QT Optoelectronics™	TINYOPTO™
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FACT®	Motion-SPM™	SPM®	µSerDes™
FAST®	OPTOLOGIC®	STEALTH™	UHC®
FastvCore™	OPTOPLANAR®	SuperFET™	UniFET™
FPS™	 ®	SuperSOT™-3	VCX™
FRFET®	PDP-SPM™	SuperSOT™-6	
Global Power ResourceSM	Power220®		

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